

Isc N-Channel MOSFET Transistor**TK65A10N1, ITK65A10N1****• FEATURES**

- Low drain-source on-resistance:
 $R_{DS(ON)} = 4.8\text{m}\Omega$ ($V_{GS} = 10\text{ V}$)
- Enhancement mode:
 $V_{th} = 2.0\text{ to }4.0\text{ V}$ ($V_{DS} = 10\text{ V}$, $I_D = 1.0\text{ mA}$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

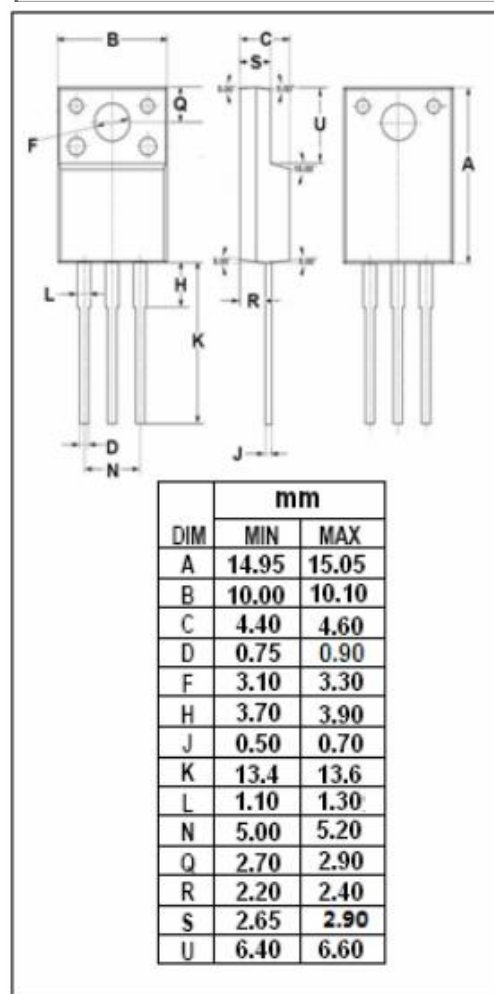
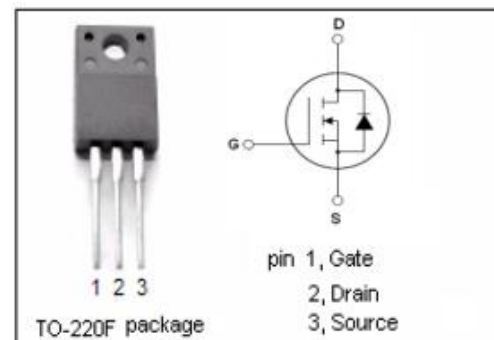
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	65	A
I_{DM}	Drain Current-Single Pulsed	296	A
P_D	Total Dissipation @ $T_c = 25^\circ\text{C}$	45	W
T_j	Max. Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	2.77	$^\circ\text{C/W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ\text{C/W}$



Isc N-Channel MOSFET Transistor**TK65A10N1, ITK65A10N1****ELECTRICAL CHARACTERISTICS****T_C=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	100			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D =1.0mA	2.0		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =32.5A			4.8	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 100V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =65A, V _{GS} = 0 V			1.2	V

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